



SiGe WIDEBAND DIRECT MODULATOR RFIC, 100 - 4000 MHz

Electrical Specifications, (continued)

Parameter	Conditions	Min.	Тур.	Max.	Units
RF Output	RF Output				
RF Frequency Range		100		4000	MHz
RF Return Loss			15		dB
LO Input	LO Input				
LO Frequency Range		100		4000	MHz
LO Input Power		-6	0	+6	dBm
LO Port Return Loss			15		dB
Baseband Input Port					
Baseband Port Bandwidth	3 dB Bandwidth with 50Ω source.	DC		700	MHz
Baseband Input DC Voltage (Vbbdc)		+1.4	+1.5	+1.6	V
Baseband Input DC Bias Current (Ibbdc)	Single-ended.		90		μΑ
Single-ended Baseband Input Capacitance	De-embed to the lead of the device.		4.5		pF
DC Power Requirements See Test Conditions Below					
Supply Voltage (Vcc1, Vcc2)		+4.5	+5.0	+5.5	V
Supply Current (Icc1, Icc2)			168		mA

Test Conditions: Unless Otherwise Specified, the Following Test Conditions Were Used

Parameter	Condition
Temperature	+25 °C
Baseband Input Frequency	200 kHz
Baseband Input DC Voltage (Vbbdc)	+1.5V
Baseband Input AC Voltage (Peak to Peak Differential, I and Q)	1.6V
Baseband Input AC Voltage for OIP3 Measurement (Peak to Peak Differential, I and Q)	800 mV per tone @ 150 & 250 kHz
Frequency Offset for Output Noise Measurements	20 MHz
Supply (Vcc1, Vcc2)	+5.0V
LO Input Power	0 dBm
LO Input Mode	Single-Ended through LON
Mounting Configuration	Refer to HMC497LP4 Application Schematic Herein
Sideband & Carrier Feedthrough	Uncalibrated

Calibrated vs. Uncalibrated Test Results

During the Uncalibrated Sideband and Carrier Suppression tests, care is taken to ensure that the I/Q signal paths from the Vector Signal Generator (VSG) to the Device Under Test (DUT) are equal. The "Uncalibrated, +25 $^{\circ}$ C" Sideband and Carrier Suppression plots were measured at room temperature, while the "Uncalibrated, over Temperature" Sideband and Carrier Suppression plots represent the worst case uncalibrated suppression levels measured at T= -40 $^{\circ}$ C, +25 $^{\circ}$ C, and +85 $^{\circ}$ C.

The "Calibrated, +25 °C" Sideband Suppression data was plotted after a manual adjustment of the I/Q amplitude balance and I/Q phase offset (skew) at +25 °C, and at each LO input power level. The +25 °C adjustment settings were held constant during tests over temperature. The "Calibrated, over Temperature" plots represent the worst case calibrated Sideband Suppression levels at T=-40 °C, +25 °C, and +85 °C.

The "Calibrated, +25 °C" Carrier Suppression data was plotted after a manual adjustment of the lp/ln & Qp/Qn DC offsets at +25 °C, and at each LO input power level. The +25 °C adjustment settings were held constant during tests over temperature. The "Calibrated, over Temperature" plots represent the worst case Carrier Suppression levels measured at T= -40 °C, +25 °C, and +85 °C.

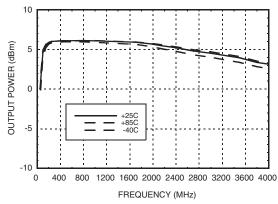
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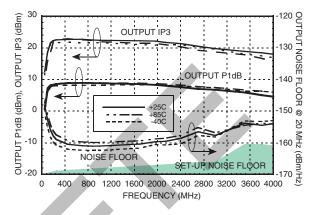


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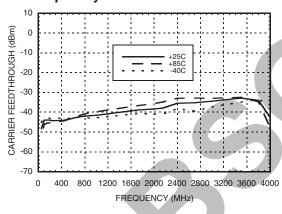
Wideband Performance vs. Frequency



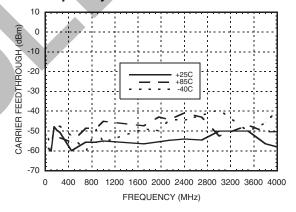
Output IP3, P1dB & Noise Floor @ 20 MHz Offset vs. Frequency



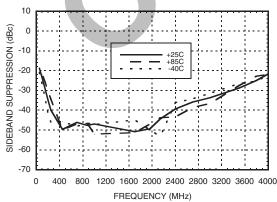
Uncalibrated Carrier Feedthrough [1] vs. Frequency



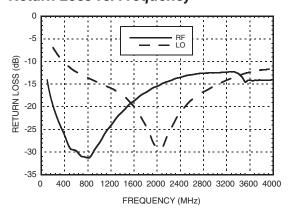
Calibrated Carrier Feedthrough [1] vs. Frequency



Sideband Suppression vs. Frequency



Return Loss vs. Frequency



[1] See note titled "Calibrated vs. Uncalibrated test results" herein.

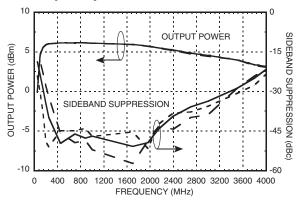
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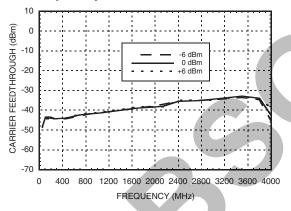




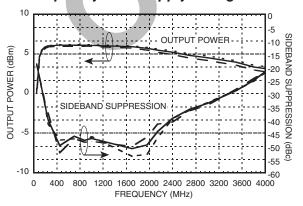
Wideband Performance vs. Frequency Over LO Power [3]



Uncalibrated Carrier Feedthrough [2] vs. Frequency



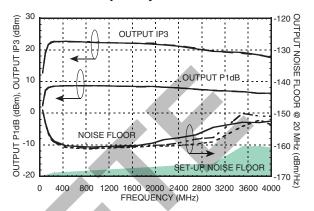
Wideband Performance vs. Frequency Over Supply Voltage [1]



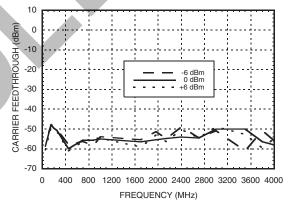
- [1] See note titled "Calibrated vs. Uncalibrated test results" herein.
- [2] Supply voltage from +4.5 to +5.5V.
- [3] LO Power from -6 dBm to +6 dBm

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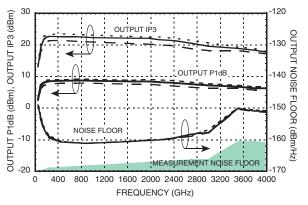
Output IP3, P1dB & Noise Floor @ 20 MHz Offset vs. Frequency Over LO Power [3]



Calibrated Carrier Feedthrough [2] vs. Frequency



Output IP3, P1dB & Noise Floor @ 20 MHz vs. Offset Frequency Over Supply Voltage [1]



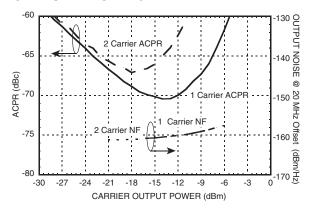
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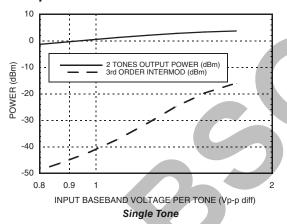




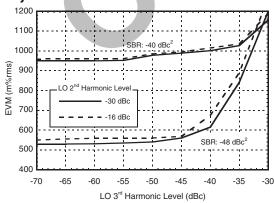
ACPR & Output Noise for W-CDMA @ 2140 MHz



Compression Characteristic @ 2140 MHz

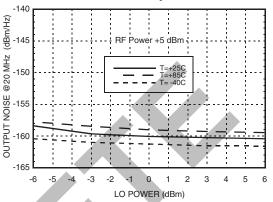


EVM vs. LO Harmonic Level & Sideband Rejection for EDGE @ 900 MHz

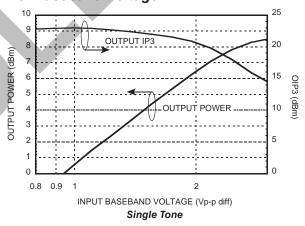


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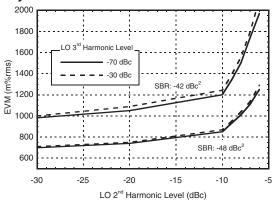
Output Noise @ 20 MHz Offset vs. LO Power Over Temperature



Power & Linearity @ 2140 MHz vs. Baseband Voltage



EVM vs. LO Harmonic Level & Sideband Rejection for EDGE @ 1900 MHz



Note 1: W-CDMA (Modulation Set-up for ACPR Mode); The Baseband I and Q input signals were generated using "Test Model 1 with 64 channels" settings in the Agilent E3844C.

Note 2: The I/Q baseband amplitude and phase inputs were offset to achieve Sideband Rejection (SBR) levels. LO = +6 dBm, SSB Power = 0 dBm

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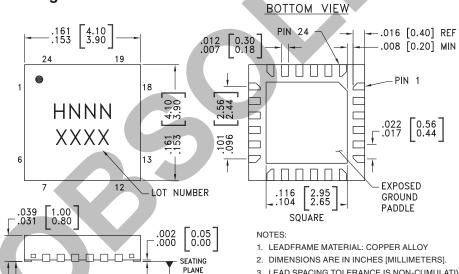
SiGe WIDEBAND DIRECT **MODULATOR RFIC, 100 - 4000 MHz**

Absolute Maximum Ratings

Vcc1, Vcc2	0V to +6V
LO Input Power	+18 dBm
Baseband Input Voltage (AC + DC) (Reference to GND)	0.0V to +2.8V
Channel Temperature	150 °C
Continuous Pdiss (T = 85°C) (Derate 30 mW/°C above 85°C)	1.8 Watts
Thermal Resistance (R _{th}) (junction to lead)	34 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



Outline Drawing



-C-

- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

Package Information

0.003[0.08] C

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC497LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H497 XXXX
HMC497LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H497 XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX

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Pin Descriptions

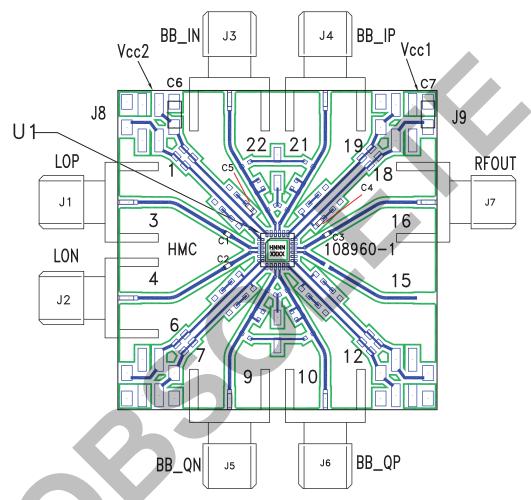
Pin Number	Function	Description	Interface Schematic
1,6, 7, 13, 15	N/C	Not connected.	
2, 5, 8, 11, 12, 14, 17, 19, 20, 23	GND	These pins and the ground paddle should be connected to a high quality RF/DC ground.	O GND
3, 4	LOP, LON	LO inputs. Need DC decoupling capacitors. The ports could be driven single ended or differentially.	Vcc O OLO
9, 10	QN, QP	Q channel differential baseband input. These high impedance ports should be biased around 1.5V DC. Nominal recommended baseband input is around 1.6V pp differential.	Qn,Qp 50 Ω
16	RFOUT	RF output. 50 Ohms. Needs DC blocking capacitor.	OVcc1
18	Vcc1	Supply voltage for the mixer and output stages 79mA @ +5.0V.	Vcc1 O OUTPUT STAGE L = L
21, 22	IP, IN	I channel differential baseband input. These high impedance ports should be at the same bias voltage (VbbDC) as Qn & Qp.	Ip,In 70 Ω
24	Vcc2	Supply voltage for the LO stage 88mA @ +5V.	Vcc2 O———————————————————————————————————





SiGe WIDEBAND DIRECT MODULATOR RFIC, 100 - 4000 MHz

Evaluation PCB



List of Materials for Evaluation PCB 108962 [1]

Item	Description	
J1 - J7	PC Mount SMA Connector	
J8, J9	DC Molex Connector	
C1 - C3	100 pF Chip Capacitor, 0402 Pkg.	
C4, C5	1000 pF Chip Capacitor, 0402 Pkg.	
C6, C7	4.7 uF, Case A, Tantulum	
U1	HMC497LP4 Modulator	
PCB [2]	108960 Eval Board	

[1] Reference this number when ordering complete evaluation PCB $\,$

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

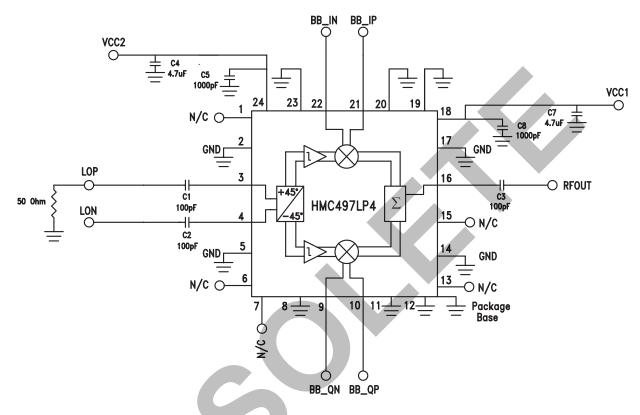


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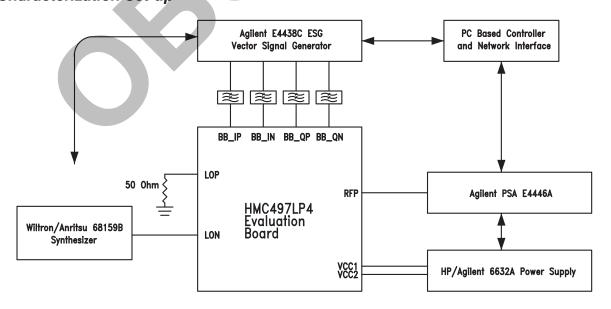


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Application & Evaluation PCB Schematic



Characterization Set-up

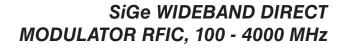


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Notes:

